AUTOMOTIV

COMPLIANT HALOGEN

FREE



## Vishay General Semiconductor

# High Current Density Surface-Mount Schottky Barrier Rectifier



#### **DESIGN SUPPORT TOOLS AVAILABLE**



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 6.0 A			
$V_{RRM}$	40 V			
I <sub>FSM</sub>	150 A			
E <sub>AS</sub>	20 mJ			
$V_F$ at $I_F = 6.0$ A	0.40 V			
T <sub>J</sub> max.	125 °C			
Package	SMPC (TO-277A)			
Circuit configuration	Common cathode			

#### **FEATURES**

- Very low profile typical height of 1.1 mm
- · Ideal for automated placement
- · Low forward voltage drop, low power losses
- · High efficiency
- · Low thermal impedance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
  - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

#### TYPICAL APPLICATIONS

For use in low voltage high frequency inverters, freewheeling, DC/DC converters and polarity protection applications.

#### **MECHANICAL DATA**

Case: SMPC (TO-277A)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Base P/NHM3\_X - halogen-free, RoHS-compliant and

AEC-Q101 qualified

("\_X" denotes revision code e.g. A, B,....)

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test, HM3 suffix meets JESD 201 class 2 whisker test

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	SS12P4C	UNIT		
Device marking code			S124C			
Maximum repetitive peak reverse voltage		$V_{RRM}$	40	V		
Maximum average forward rectified current (fig. 1) (1)	total device	I <sub>F(AV)</sub>	12	Α		
	per diode		6.0			
Maximum average forward rectified current (2)	total device	I <sub>F(AV)</sub>	3.5	А		
Peak forward surge current 10 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	150	А		
Non-repetitive avalanche energy at T <sub>J</sub> = 25 °C, L = 60 mH per diode		E <sub>AS</sub>	20	mJ		
Peak repetitive reverse current at $t_p$ = 2 $\mu$ s, 1 kHz, at $T_J$ = 25 $^{\circ}$ C per diode		I <sub>RRM</sub>	1.0	А		
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +125	°C		

#### Notes

- (1) Mounted on 30 mm x 30 mm Al PCB with 50 mm x 25 mm x 100 mm fin heat sink
- (2) Free air, mounted on recommended copper pad area



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I <sub>F</sub> = 1 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.34	-	. v	
	I <sub>F</sub> = 3 A			0.40	-		
	I <sub>F</sub> = 6 A			0.46	0.52		
	I <sub>F</sub> = 1 A	T <sub>A</sub> = 100 °C		0.24	-		
	I <sub>F</sub> = 3 A			0.31	-		
	I <sub>F</sub> = 6 A			0.40	0.45		
Reverse current per diode	Rated V <sub>R</sub>	T <sub>A</sub> = 25 °C T <sub>A</sub> = 100 °C	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	129	500	μΑ
	nated V <sub>R</sub>		IR <sup>(−)</sup>	11.9	25	mA	
Typical junction capacitance per diode	4.0 V, 1 MHz		CJ	400	-	pF	

#### **Notes**

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width  $\leq$  40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	SS12P4C	UNIT	
Typical thermal resistance	R <sub>0JA</sub> (1)	100	°C/W	
	$R_{\theta JM}$ (2)	3		

#### Notes

- $^{(1)}$  Free air, mounted on recommended copper pad area. Thermal resistance  $R_{\theta JA}$  junction to ambient
- (2) Mounted on 30 mm x 30 mm Al PCB with 50 mm x 25 mm x 100 mm fin heat sink. Thermal resistance R<sub>0JM</sub> junction to mount

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
SS12P4C-M3/86A	0.10	86A	1500	7" diameter plastic tape and reel	
SS12P4C-M3/87A	0.10	87A	6500	13" diameter plastic tape and reel	
SS12P4CHM3_A/H (1)	0.10	Н	1500	7" diameter plastic tape and reel	
SS12P4CHM3_A/I (1)	0.10	I	6500	13" diameter plastic tape and reel	

#### Note

(1) AEC-Q101 qualified

### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

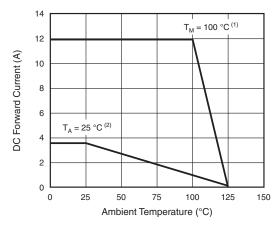


Fig. 1 - Maximum Forward Current Derating Curve

#### Notes

- Mounted on 30 mm x 30 mm Al PCB with 50 mm x 25 mm x 100 mm fin heat sink, T<sub>M</sub> measured at the terminal of cathode band (R<sub>0JM</sub> = 3 °C/W)
- Free air, mounted on recommended copper pad area  $(R_{\theta JA} = 100 \ ^{\circ}\text{C/W})$



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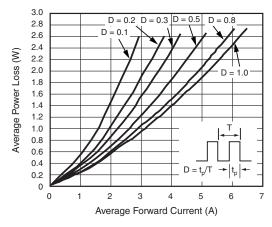


Fig. 2 - Forward Power Loss Characteristics Per Diode

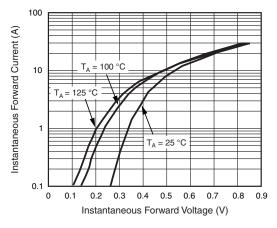


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

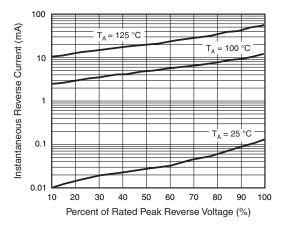


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

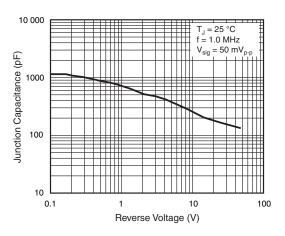


Fig. 5 - Typical Junction Capacitance Per Diode

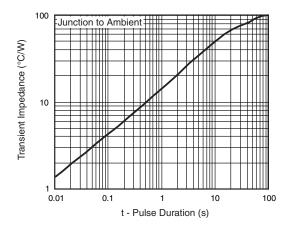
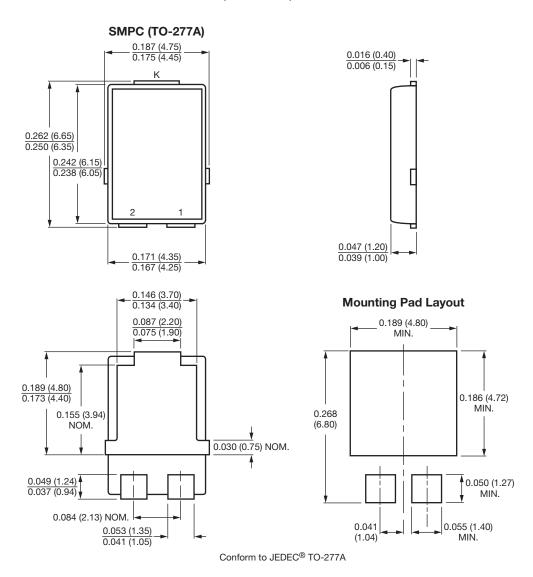


Fig. 6 - Typical Transient Thermal Impedance Per Diode



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#### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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